

Enhanced photocatalytic performance of nanosized coupled ZnO/SnO₂ photocatalysts for methyl orange degradation

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Abstract

Nanosized coupled ZnO/SnO₂ photocatalysts with different Sn contents were prepared using the coprecipitation method, and characterized by X-ray diffraction, specific surface area and UV-Vis diffuse reflectance spectroscopy. The phases, mean grain sizes and band gap energy of the coupled ZnO/SnO₂ photocatalysts varied with the Sn contents and the calcination temperatures. The photocatalytic activities of the coupled ZnO/SnO₂ photocatalysts, evaluated using the photodegradation of methyl orange as a probe reaction, were also found to be related to the calcination temperatures and the Sn contents. The photocatalytic activities of the coupled ZnO/SnO₂ photocatalysts decreased with the increasing calcination temperatures. The maximum photocatalytic activity of the coupled ZnO/SnO₂ photocatalyst, which is about 1.3 times the photocatalytic activity of ZnO and 21.3 times that of SnO₂, was observed with a Sn content of 33.3 mol% under calcination at 500 °C for 10 h. The enhancement of the photocatalytic activity might arise from the hetero-junctions ZnO/SnO₂ in the coupled oxides. The photo-stability of the ZnO/SnO₂ photocatalyst was also studied.

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1. Introduction

Photocatalytic degradation of organic pollutants in water and air using semiconductors, such as TiO₂ and ZnO, has attracted extensive attention in the past two decades [1]. Previous studies have proved that such semiconductors can degrade most kinds of persistent organic pollutants, such as detergents, dyes, pesticides and volatile organic compounds, under UV-irradiation. However, the fast recombination rate of the photogenerated electron/hole pairs hinders the commercialization of this technology [1]. It is of great interest to improve the photocatalytic activity of semiconductors for the degradation of organic compounds in water and air. In the past decade years, there are a number of studies related to the photocatalytic activity of TiO₂ or ZnO coupled with

metal oxides, like SnO₂ [2,3], WO₃ [4], Fe₂O₃ [5], ZrO₂ [6] and some rare earth oxides [7], for the purpose of improving the photocatalytic activity of TiO₂ or ZnO. Coupled semiconductor photocatalysts may increase the photocatalytic efficiency by increasing the charge separation and extending the photo-responding range. At the same time, their physical and optical properties are greatly modified [4].

The aim of this study is to optimize the preparation for the coupled ZnO/SnO₂ photocatalysts. For that purpose, a series of nanosized coupled ZnO/SnO₂ photocatalysts with different Sn contents were prepared and their photocatalytic activities were evaluated using methyl orange as a model organic compound. Furthermore, the diffuse reflectance spectra of the coupled ZnO/SnO₂ photocatalysts were measured, and their band gap energies were calculated according to the spectra. The effect of the heat-treating condition on the photocatalytic activities of the coupled ZnO/SnO₂ photocatalysts has been studied. The photo-stability of

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the coupled ZnO/SnO₂ photocatalyst with a Sn content of 33.3 mol% has also been examined.

2. Experimental

2.1. Preparation of nanosized photocatalysts

The nanosized coupled ZnO/SnO₂ photocatalysts were prepared using the coprecipitation method. SnCl₄·5H₂O and ZnSO₄·7H₂O (Analytic reagent grade, or A.R.) were used as the starting materials, and NaOH (A.R.) was used as the coprecipitant without further purification. ZnSO₄·7H₂O and SnCl₄·5H₂O in the molar ratios of 20:1, 2:1, 1:1, 1:2 and 1:20 were dissolved in a minimum amount of deionized water for the preparation of the coupled ZnO/SnO₂ photocatalysts with the Zn/Sn molar ratios of 20:1, 2:1, 1:1, 1:2 and 1:20, labeled by Z₂₀S₁, Z₂S₁, Z₁S₁, Z₁S₂ and Z₁S₂₀, respectively. Then the 4 mol l⁻¹ NaOH solution was added, respectively, into the above solutions to adjust the pH to about 7, and the white amorphous precipitates were formed. The precipitates were filtered and washed with deionized water until no SO₄²⁻ and Cl⁻ were found in the filtrates. Then the wet powders were dried at about 100 °C in air to form the precursors of the coupled ZnO/SnO₂ photocatalysts. Finally the precursors were calcined in air to prepare the nanosized photocatalysts. The nanosized ZnO (Z) and SnO₂ (S) were prepared using the same procedure as mentioned above except that the starting materials are ZnSO₄·7H₂O for ZnO and SnCl₄·5H₂O for SnO₂, respectively.

2.2. Characterization of photocatalysts

To determine the crystal phase composition of the coupled ZnO/SnO₂ photocatalyst powders, X-ray powder diffraction (XRD) analysis was carried out at room temperature using a Rigaku D/max-1200 diffractometer with Cu K α radiation ($\lambda = 0.15418$ nm), over the 2θ collection range of 10–60°. The accelerating voltage of 40 kV, emission current of 30 mA and the scanning speed of 4° min⁻¹ were used. UV-Vis diffuse reflectance spectra (UV-Vis DRS) were recorded in air at room temperature in the wavelength range of 200–700 nm using a Hitachi U-3010 spectrophotometer with an integrating sphere. The pure powdered BaSO₄ was used as a reference sample. Specific surface areas (S_{BET}) were measured with Brunauer–Emmett–Teller (BET) method using a Quantachrome NOVA/1000 gas (N₂) analyzer.

2.3. Photocatalytic activity measurements

The photodegradation of methyl orange (MO) in aqueous solution was monitored in the presence of various coupled ZnO/SnO₂ photocatalyst powders. The MO is A.R. grade and was used as supplied. The photocatalytic reactor consists of two parts: a 100 ml Pyrex glass bottle and a 300 W high pressure Hg lamp with a maximum emission at about

365 nm, which was positioned parallel to the Pyrex glass bottle. In all experiments, the photocatalytic reaction temperature was kept at about 35 °C.

Reaction suspensions were prepared by adding photocatalyst powders into 100 ml MO solutions. The suspensions were ultrasonically sonicated for 15 min and then magnetically stirred in dark for 30 min to ensure an adsorption/desorption equilibrium prior to the UV-irradiation. The suspensions containing MO and photocatalysts were then irradiated by the UV light with continuous stirring.

Analytical samples were drawn from the reaction suspensions after various reaction times and centrifuged at 9000 rpm for 10 min, and then filtered through a 0.2 μm millipore filter to remove the particles. The MO concentrations of the filtrates were analyzed by UV-Vis spectroscopy (Thermo Spectronic/HeLios α) at its maximum absorption wavelength of 464 nm. Total organic carbon (TOC) measurements of the filtrates were conducted using a Dohrmann/Phoenix 8000/UV-Persulfate TOC analyzer.

3. Results and discussion

3.1. Phase and main grain size of photocatalysts

The precursors of the coupled ZnO/SnO₂ photocatalysts were calcined at 500, 700 and 900 °C for 10 h to prepare the photocatalysts. For brevity, only the XRD patterns of the coupled ZnO/SnO₂ photocatalyst powders with different Sn contents calcined at 700 °C for 10 h are shown in Fig. 1.

The phases and the mean grain sizes of the coupled ZnO/SnO₂ photocatalysts were determined according to the XRD results (Table 1). The mean grain sizes were estimated by using the Scherrer formula [8] and selecting the crystal planes of (1 0 1), (1 1 0) and (3 1 1) for ZnO, SnO₂ and Zn₂SnO₄, respectively.

It can be seen from Table 1 that for the pure SnO₂ (cassiterite) and ZnO (zincite) samples, no changes in the phases were observed, but the mean grain sizes of the SnO₂ and the ZnO became larger with the increasing calcination tem-

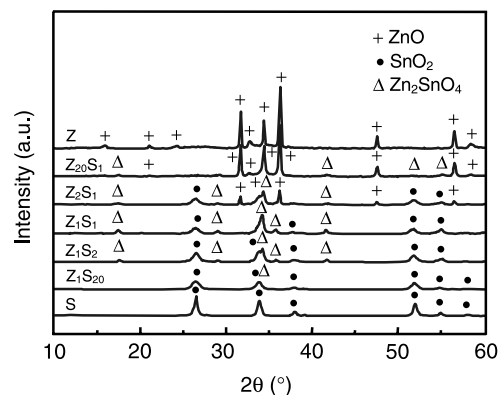


Fig. 1. XRD patterns of the coupled ZnO/SnO₂ photocatalyst powders calcined at 700 °C for 10 h.

Table 1
Relationship of phase, mean grain size, composition and calcination temperature

| Sample | Sn content ^a (mol%) | Phase/mean grain size (nm) | | |
|--------------------------------|-----------------------------------|---|--|---|
| | | 500 °C ^{b,c} | 700 °C ^{b,c} | 900 °C ^{b,c} |
| Z | 0 | ZnO/60.3 | ZnO/115.8 | ZnO/215.2 |
| Z ₂₀ S ₁ | 4.8 | ZnO/51.9 SnO ₂ /n.d. ^d | ZnO/88.6 – Zn ₂ SnO ₄ /a few | ZnO/100.4 – Zn ₂ SnO ₄ /a few |
| Z ₂ S ₁ | 33.3 | ZnO/48.6 SnO ₂ /2.0 – | ZnO/79.3 SnO ₂ /10.8 Zn ₂ SnO ₄ /71.3 | ZnO/a few SnO ₂ /a few Zn ₂ SnO ₄ /115.2 |
| Z ₁ S ₁ | 50 | ZnO/8.5 SnO ₂ /2.7 – | – SnO ₂ /11.0 Zn ₂ SnO ₄ /36.5 | – SnO ₂ /77.4 Zn ₂ SnO ₄ /99.8 |
| Z ₁ S ₂ | 66.7 | ZnO/3.1 SnO ₂ /3.6 – | – SnO ₂ /14.6 Zn ₂ SnO ₄ /28.3 | – SnO ₂ /58.5 Zn ₂ SnO ₄ /88.1 |
| Z ₁ S ₂₀ | 95.2 | ZnO/n.d. SnO ₂ /6.9 – | – SnO ₂ /17.2 Zn ₂ SnO ₄ /a few | – SnO ₂ /50.7 Zn ₂ SnO ₄ /a few |
| S | 100 | SnO ₂ /11.4 | SnO ₂ /25.8 | SnO ₂ /44.6 |

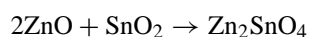
^a Molar fraction of Sn in total Zn and Sn (the same hereinafter).

^b Calcination temperature.

^c All samples were calcined for 10 h.

^d Could not be detected.

perature. For all the coupled ZnO/SnO₂ photocatalysts, a solid reaction between the ZnO and SnO₂ to form an inverse spinel-type Zn₂SnO₄ phase (JCPDS 74-2184) took place at 700 °C and continued at 900 °C. The reaction between ZnO and SnO₂ to form Zn₂SnO₄ is expressed as follows [9]:



Therefore, the formation temperature of Zn₂SnO₄ with the coprecipitation method is about 700 °C, which is about 300 °C lower than that (about 1000 °C) with the solid reaction method [9,10]. For Z₁S₁, Z₁S₂ and Z₁S₂₀, the phase compositions were the mixture of ZnO and SnO₂ when calcining at 500 °C for 10 h (ZnO for Z₁S₂₀ was not detected by XRD due to its low content), but became the mixture of SnO₂ and Zn₂SnO₄ because all the ZnO had reacted with SnO₂ when calcining at 700 and 900 °C for 10 h. For Z₂S₁, when calcining at 500 °C for 10 h the phase compositions were also the mixture of SnO₂ and ZnO, but when calcining at 700 and 900 °C for 10 h the phase compositions were the mixture of ZnO, SnO₂ and Zn₂SnO₄, and only a few ZnO and SnO₂ remained after calcination for 10 h at 900 °C. It can be estimated approximately from the XRD intensities that about 60 and 95 mol% of total ZnO had reacted with SnO₂ to form Zn₂SnO₄ after the Z₂S₁ was calcined at 700 and 900 °C for 10 h. For Z₂₀S₁, when calcining at 500 °C for 10 h, only ZnO could be observed. SnO₂ was not detected because of its very low content. After calcining at 700 and 900 °C for 10 h, the powders were the mixture of

ZnO and Zn₂SnO₄, since all the SnO₂ had reacted with ZnO to form Zn₂SnO₄.

It can be seen from Table 1 that the mean grain size of the ZnO in the pure ZnO sample was always much larger than that of the SnO₂ in the pure SnO₂ sample under the same calcination conditions. This is another fact that ZnO sinters more easily, and therefore it tends to have larger grain size than SnO₂ [11]. For the coupled ZnO/SnO₂ photocatalysts, not only the growth of the ZnO grain was inhibited by the SnO₂ coexisted, but also the inhibitive effect enhanced as the SnO₂ content increased. This is in agreement with the literature results that the addition of SnO₂ into ZnO causes a decrease in the mean grain size of ZnO [12,13]. Table 1 also indicates that when calcining at 500 and 700 °C, the growth of the SnO₂ grain was also inhibited by the ZnO coexisted, and the inhibitive effect enhanced as the ZnO content increased. This is similar to the case of ZnO and agrees with the literature result [14]. A possible explanation is that both the sintering between particles and the growth of the SnO₂ grain proceeded through a surface diffusion mechanism, and the ZnO particles could disperse on the SnO₂ surface [14], leading the growth of the SnO₂ grain to be inhibited by the ZnO. By contrast, when calcining at 900 °C, the ZnO coexisted seemed to favor the growth of the SnO₂ grain. This may be due to that the Zn₂SnO₄ formed promoted the growth of the SnO₂ grain under such high calcination temperature as 900 °C.

3.2. UV-Vis DRS and band gap energy

The room temperature UV-Vis diffuse reflectance spectra of the S, Z₁S₂₀, Z₁S₂, Z₁S₁, Z₂S₁, Z₂₀S₁ and Z powders calcined at 500, 700 and 900 °C for 10 h were displayed in Fig. 2. The wavelengths of absorption edges were determined by extrapolating the horizontal and sharply rising portions of the curve and defining the edge as the wavelength of the intersection [15]. The absorption edges thus determined are given in Table 2. The band gap energies (E_g) calculated on the basis of the corresponding absorption edges are shown in Fig. 3 [16]. As shown in Table 1, the coupled ZnO/SnO₂ photocatalysts calcined at 500, 700 and 900 °C for 10 h are the mixtures of ZnO, SnO₂ and/or Zn₂SnO₄, so the band gap energies of the coupled ZnO/SnO₂ pho-

Table 2
Relationship of composition, calcination temperature and absorption edge

| Sample | Sn content (mol%) | Absorption edge (nm) | | |
|--------------------------------|----------------------|-----------------------|-----------------------|-----------------------|
| | | 500 °C ^{a,b} | 700 °C ^{a,b} | 900 °C ^{a,b} |
| Z | 0 | 388.9 | 386.9 | 390.6 |
| Z ₂₀ S ₁ | 4.8 | 391.2 | 387.5 | 386.3 |
| Z ₂ S ₁ | 33.3 | 397.5 | 388.7 | 361.1 |
| Z ₁ S ₁ | 50 | 402.8 | 389.9 | 353.4 |
| Z ₁ S ₂ | 66.7 | 415.6 | 397.2 | 358.9 |
| Z ₁ S ₂₀ | 95.2 | 466.1 | 434.2 | 373.3 |
| S | 100 | 485.3 | 482.5 | 463.1 |

^a Calcination temperature.

^b All samples were calcined for 10 h.

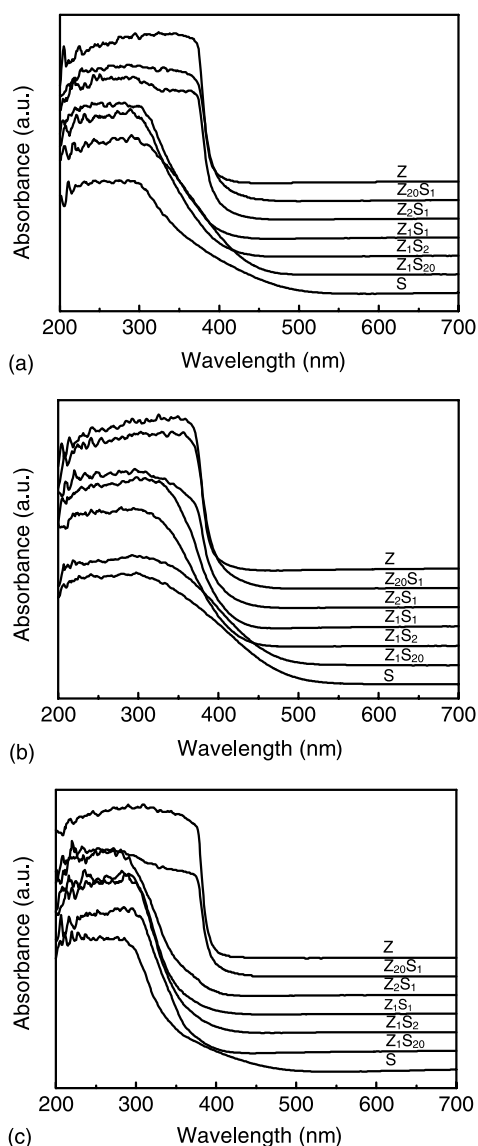


Fig. 2. UV-Vis diffuse reflectance absorption spectra of the coupled ZnO/SnO₂ photocatalyst powders calcined at (a) 500, (b) 700 and (c) 900 °C for 10 h.

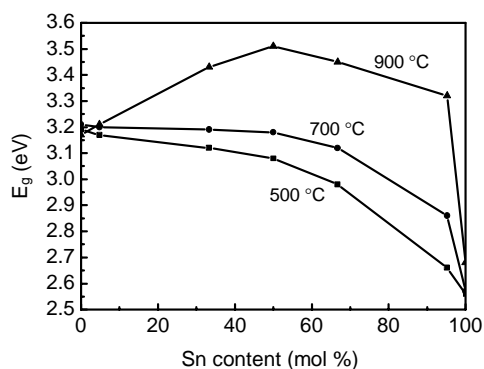
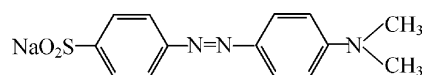


Fig. 3. Effect of the Sn content on the band gap energy of the coupled ZnO/SnO₂ photocatalysts calcined at 500, 700 and 900 °C for 10 h.

photocatalysts should originate from the overlapping of the corresponding ZnO, SnO₂ and/or Zn₂SnO₄ components in the coupled oxides. It can be seen from Table 2 and Fig. 3 that the absorption edge of the coupled ZnO/SnO₂ photocatalyst, or the band gap energy, changed with the Sn content and the calcination temperature. When calcining at 500 and 700 °C, the band gap energy of the coupled ZnO/SnO₂ photocatalyst decreased with the increasing SnO₂ content. When calcining at 900 °C, however, the band gap energy increased to a maximum at the Sn content of 50 mol% and then decreased as the Sn content further increased. For the coupled ZnO/SnO₂ photocatalyst with a fixed Sn content, the band gap energy increased with the calcination temperature. These changes in band gap energy may be due to the change in the ratio of the ZnO, SnO₂ and/or Zn₂SnO₄ in the coupled ZnO/SnO₂ photocatalysts, which is controlled by the Sn content and the calcination conditions. The band gap energies of ZnO, SnO₂ and Zn₂SnO₄ were reported to be 3.2 eV [16], 3.2 eV [16] and 3.4 eV [17], respectively. The band gap energies of the pure ZnO samples calcined at 500, 700 and 900 °C for 10 h were measured to be 3.19, 3.20 and 3.17 eV, respectively, which are in reasonable agreement with the accepted literature value of 3.2 eV [16] taking into account the experimental errors, indicating that the band gap energy of the ZnO has no relation with the calcination temperature. It can also be seen from Fig. 2 that the absorption curves of the SnO₂ samples calcined at 500, 700 and 900 °C for 10 h, and those of the Z₁S₂₀ samples calcined at 500 and 700 °C for 10 h, displayed significant energy tail. But the energy tail of the Z₁S₂₀ disappeared when the calcination temperature was increased to 900 °C. This indicates that the SnO₂ samples calcined at 500, 700 and 900 °C and the Z₁S₂₀ samples calcined at 500 and 700 °C, showed indirect transition, whereas the Z₁S₂₀ sample calcined at 900 °C only showed direct transition [18–20]. It was reported that SnO₂ is an n-type semiconductor oxide not only with the direct band gap energy of 3.5–3.9 eV [18–22] but also with the indirect band gap energy of around 2.6 eV [18–20]. The indirect band gap energies of the SnO₂ samples calcined at 500, 700 and 900 °C for 10 h were measured to be 2.56, 2.57 and 2.68 eV, respectively, indicating that the indirect band gap energy of the SnO₂ increased with the increasing calcination temperature. It should be noted that the above three indirect band gap energies of the SnO₂ are reasonable, because the colors (light-yellow) of the SnO₂ samples were consistent with the corresponding optical spectra [23].

3.3. Photocatalytic activity

The structural formula of methyl orange is shown in Scheme 1.



Scheme 1.

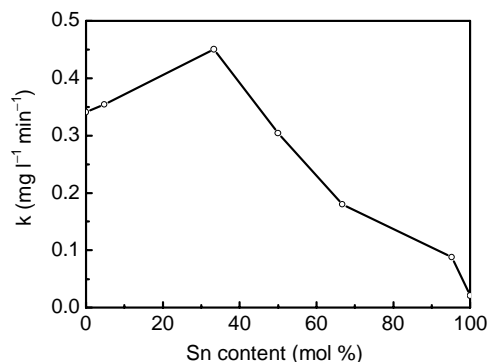


Fig. 4. The photocatalytic activity as a function of the Sn content for the coupled ZnO/SnO₂ photocatalysts calcined at 500 °C for 10 h (photocatalytic reaction rate constants (k) were calculated considering the initial 20 min of irradiation, i.e. $k = (C_0 - C_{20})/20$, where C_0 and C_{20} are the equilibrium concentrations of MO before and after 20 min UV-irradiation, respectively). Photocatalysts: 2.5 g l⁻¹; MO: 20 mg l⁻¹.

The photocatalytic activities of the coupled ZnO/SnO₂ photocatalysts with different Sn contents calcined at 500 °C for 10 h is shown in Fig. 4. It can be seen from Fig. 4 that pure SnO₂ showed very low photocatalytic activity and pure ZnO showed higher photocatalytic activity, which agrees with the previous report [1,16]. Therefore, the Sn content should be an important factor affecting the photocatalytic activity of the coupled ZnO/SnO₂ photocatalyst. It can be seen that the Z₂₀S₁ and Z₂S₁ photocatalysts displayed higher photocatalytic activity than pure ZnO and SnO₂, and the photocatalytic activity of the coupled ZnO/SnO₂ photocatalyst changed with the Sn content. The optimum Sn content was found at 33.3 mol%, at which the photocatalytic activity of the coupled ZnO/SnO₂ photocatalyst is about 1.3 times that of the ZnO and 21.3 times that of the SnO₂. The enhancement in the photocatalytic activity may come from the hetero-junctions ZnO/SnO₂ in the coupled ZnO/SnO₂ photocatalysts [2]. For the coupled ZnO/SnO₂ photocatalyst calcined at 500 °C for 10 h, as the Sn content increased up to 33.3 mol%, the photocatalytic activity should increase gradually due to that the number of the hetero-junctions ZnO/SnO₂ increased [2,24]. But further increasing the SnO₂ content led to a decrease in the photocatalytic activity of the coupled ZnO/SnO₂ photocatalyst because of the very low photocatalytic activity of SnO₂. The specific surface areas of the Z, Z₂₀S₁, Z₂S₁, Z₁S₁, Z₁S₂, Z₁S₂₀ and S powders calcined at 500 °C for 10 h were measured to be 6.4, 17.6, 36.1, 38.2, 48.2, 43.6 and 35.2 m² g⁻¹, respectively, indicating that the specific surface area increased as the Sn content was increased up to 66.7 mol%, which led the photocatalytic activity to increase accordingly. Therefore, for the coupled ZnO/SnO₂ photocatalysts, the maximum photocatalytic activity appeared at the Sn content of 33.3 mol% due to the above conflicting factors that affect the overall photocatalytic activity.

Fig. 5 shows the degradation kinetics of MO over the Z₂S₁ photocatalysts calcined at 500, 700 and 900 °C for 10 h. A blank experiment in the absence of the UV-irradiation but

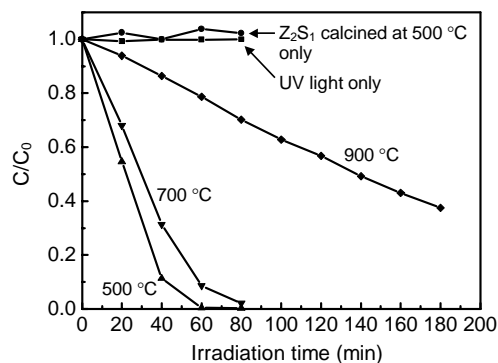


Fig. 5. Degradation kinetics of MO over the Z₂S₁ photocatalysts calcined at 500, 700 and 900 °C for 10 h (C_0 and C are the equilibrium concentrations of MO before and after UV-irradiation, respectively). Z₂S₁: 2.5 g l⁻¹; MO: 20 mg l⁻¹.

with the Z₂S₁ calcined at 500 °C for 10 h demonstrated that no MO degradation occurred. Another blank experiment in the absence of the photocatalyst but under the UV-irradiation showed that MO could not be degraded. The results of the blank experiments are as shown in Fig. 5. It can be seen from Fig. 5 that the photocatalytic activity of the Z₂S₁ decreased slightly when the calcination temperature was increased from 500 to 700 °C, but decreased significantly when the calcination temperature was increased to 900 °C. A main reason may be that the residual ZnO decreased significantly as the calcination temperature was increased: about 40 mol% of total ZnO still remained after calcination for 10 h at 700 °C, but only about 5 mol% of total ZnO remained after calcination for 10 h at 900 °C because about 95 mol% of total ZnO had reacted with the SnO₂ to form Zn₂SnO₄ with a little photocatalytic activity [25,26]. The photocatalytic activity of the Z₂S₁ calcined at 900 °C for 10 h may mostly arise from the residual ZnO (about 5 mol% of total ZnO). The specific surface areas of the Z₂S₁ photocatalysts calcined at 500, 700 and 900 °C for 10 h were measured to be 36.1, 20.5 and 2.2 m² g⁻¹, respectively. Therefore, the specific surface area of the Z₂S₁ photocatalyst decreased significantly with the increasing calcination temperature, thus led to decrease in photocatalytic activity. It can be seen from Fig. 5 that the MO solution can be decolorized completely over the Z₂S₁ calcined at 500 °C for 10 h after about 60 min UV-irradiation, indicating that the Z₂S₁ shows higher photocatalytic activity to methyl orange.

Fig. 6 shows the TOC elimination kinetics of MO over the Z₂S₁ calcined at 500 °C for 10 h. Noticeably, about 42.8% of TOC still remained after the decolorization process was completed. Moreover, the mineralization rate become very slow after the UV-irradiation of about 100 min, indicating the formation of some long-lived by-products, which have low rate constants of reactions with hydroxyl radicals. Indeed, even an extended irradiation of over 140 min did not induce a complete conversion of the organic materials to water, carbon dioxide and other inorganic species, and about 15% of TOC still remained.

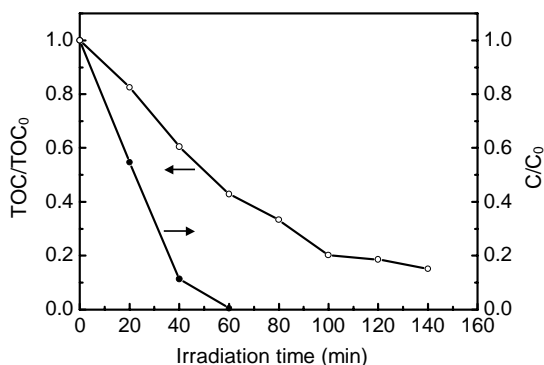


Fig. 6. TOC elimination kinetics of MO over the Z_2S_1 calcined at 500°C for 10h (TOC₀ and TOC are the total organic carbon concentrations of the MO suspensions before and after UV-irradiation, respectively). Z_2S_1 : 2.5 g l^{-1} ; MO: 20 mg l^{-1} .

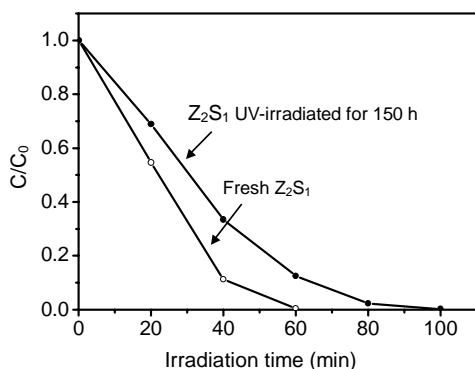


Fig. 7. Comparison for the photocatalytic activities of the Z_2S_1 calcined at 500°C for 10h before and after 150h UV-irradiation.

The photo-stability of the Z_2S_1 photocatalyst calcined at 500°C for 10h is shown in Fig. 7. It can be seen that the photocatalytic activity became lower after the photocatalyst was UV-irradiated for 150h. The XRD analysis indicates no changes in the phase composition of the photocatalyst after 150h UV-irradiation (not shown). But the XRD results cannot rule out the possibility of the formations of some amorphous products such as amorphous $Zn(OH)_2$, $SnO_2 \cdot nH_2O$, Zn and Sn with no photocatalytic activity under the UV-irradiation. It is possible that one or more of amorphous $Zn(OH)_2$, $SnO_2 \cdot nH_2O$, Zn and Sn formed under the UV-irradiation, which led to the decrease in the photocatalytic activity. But a further study is needed on this issue.

4. Conclusion

The nanosized coupled ZnO/SnO_2 photocatalysts were prepared with the coprecipitation method followed by calcinations, and their phase compositions, mean sizes and band gap energies, as well as their photocatalytic activities, were studied with regard to their Sn contents and calcination tem-

peratures. The photocatalytic activity of the coupled photocatalysts, evaluated by using MO photodegradation as a probe reaction, reached their maximum when the Sn content was about 33.3 mol% and calcination temperature was about 500°C . The hetero-junctions ZnO/SnO_2 in the coupled ZnO/SnO_2 photocatalysts might be responsible for the enhancement of their photocatalytic activity. The coupled ZnO/SnO_2 photocatalyst with a Sn content of 33.3 mol% calcined at 500°C for 10h was found to be relatively stable and an effective photocatalyst for the degradation of methyl orange.

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